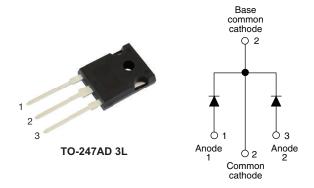


FRED Pt® Ultrafast Rectifier, 2 x 15 A



PRIMARY CHARACTERISTICS						
I _{F(AV)} 2 x 15 A						
V_{R}	400 V					
V _F at I _F	0.93 V					
t _{rr} typ.	36 ns					
T _J max.	175 °C					
Package	TO-247AD 3L					
Circuit configuration	Common cathode					

FEATURES

- Ultrafast recovery time
- · Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current

 AEC-Q101 qualified, meets JESD 201 class 1A whisker test



 Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

DESCRIPTION / APPLICATION

FRED Pt® series are the state of the art ultrafast recovery rectifiers specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diodes in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

MECHANICAL DATA

Case: TO-247AD 3L

Molding compound meets UL 94 V-0 flammability rating **Terminals:** matte tin plated leads, solderable per

J-STD-002

ABSOLUTE MAXIMUM RATINGS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Peak repetitive reverse voltage		V_{RRM}		400	V			
Average restified forward average		1		15				
Average rectified forward current total device	total device	I _{F(AV)}	Rated V _R , T _C = 149 °C	30	^			
Non-repetitive peak surge current per leg		I _{FSM}	T _C = 25 °C	200	А			
Peak repetitive forward current per leg	3	I _{FRM}	Rated V _R , T _C = 149 °C, square wave, 20 kHz	30				
Operating junction and storage tempe	ratures	T _J , T _{Stg}		-55 to +175	°C			

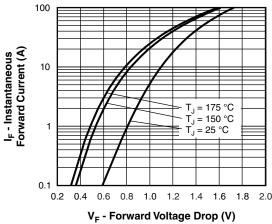
ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	L TEST CONDITIONS MIN. T		TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V_{BR}, V_{R}	I _R = 100 μA	400	-	-			
Forward voltage	V_{F}	I _F = 15 A	-	1.17	1.25	V		
	v _F	I _F = 15 A, T _J = 150 °C	-	0.93	1.12			
Reverse leakage current	I _R	$V_R = V_R$ rated	-	0.3	10			
		$T_J = 150 ^{\circ}\text{C}, V_R = V_R \text{rated}$	-	30	500	μΑ		
Junction capacitance	C _T	V _R = 400 V	-	28	-	pF		
Series inductance	L _S	Measured lead to lead 5 mm from package body	ı	12	-	nH		





DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST (MIN.	TYP.	MAX.	UNITS		
		$I_F = 1 A, dI_F/dt = 5$	$I_F = 1 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		36	-		
Reverse recovery time	t _{rr}	T _J = 25 °C	I _F = 15 A dI _F /dt = 200 A/μs V _R = 200 V	-	46	-	ns	
		T _J = 125 °C		-	80	-		
Peak recovery current	I _{RRM}	T _J = 25 °C		-	3.6	-	Α	
		T _J = 125 °C		-	8.7	-	A	
Reverse recovery charge	0	T _J = 25 °C		-	84	-	nC	
	Q _{rr}	T _J = 125 °C		-	345	ı	iiC	

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C		
Thermal resistance, junction to case per leg	R _{thJC}		-	0.8	1.5			
Thermal resistance, junction to ambient per leg	R _{thJA}	Typical socket mount		-	40	°C/W		
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth, and greased	ı	0.4	-			
Weight			ı	6.0	-	g		
Weight			ı	0.21	-	oz.		
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)		
Marking device		Case style TO-247AD 3L		30CP	U04LH			





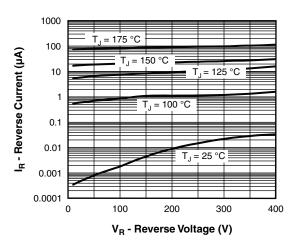


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

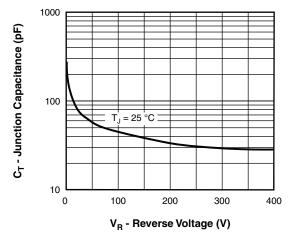


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

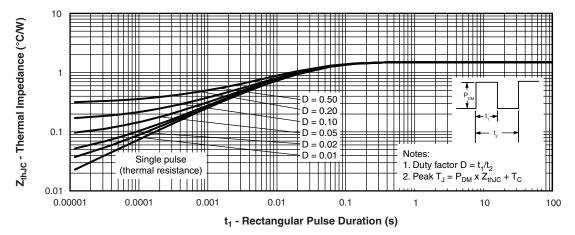
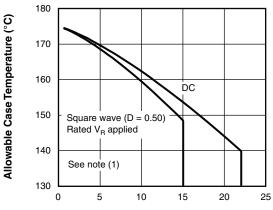


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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I_{F(AV)} - Average Forward Current (A)

Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

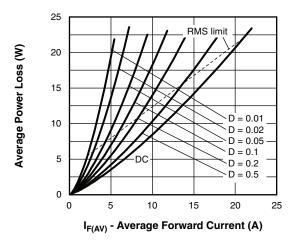


Fig. 6 - Forward Power Loss Characteristics

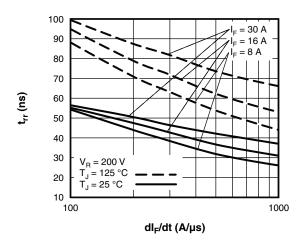


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

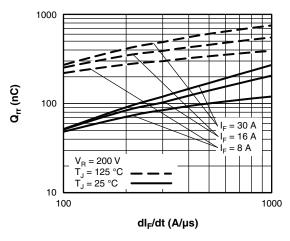
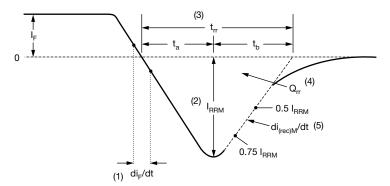


Fig. 8 - Typical Stored Charge vs. dl_F/dt

Note

 $\begin{array}{ll} \text{(1)} \ \ \text{Formula used:} \ T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \ \text{at} \ (I_{F(AV)}/D) \ (\text{see fig. 6}); \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_R \ (1 - D); \ I_R \ \text{at} \ V_{R1} = \text{rated} \ V_R \end{aligned}$



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $t_{\rm rr}$ reverse recovery time measured from zero crossing point of negative going $I_{\rm F}$ to point where a line passing through 0.75 $I_{\rm RRM}$ and 0.50 $I_{\rm RRM}$ extrapolated to zero current.
- (4) $\mathbf{Q}_{\rm rr}$ area under curve defined by $\mathbf{t}_{\rm rr}$ and $\mathbf{I}_{\rm RRM}$

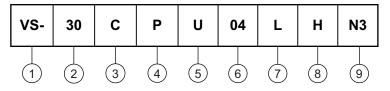
$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $di_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 9 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code



- Vishay Semiconductors product
- 2 Current rating (30 = 30 A)
- Circuit configuration: C = common cathode
- **4** TO-247AC
- 5 Ultrafast recovery
- 6 Voltage rating (04 = 400 V)
- 7 L = long lead (TO-247AD)
- 8 H = AEC-Q101 qualified
- 9 Environmental digit:
 - N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

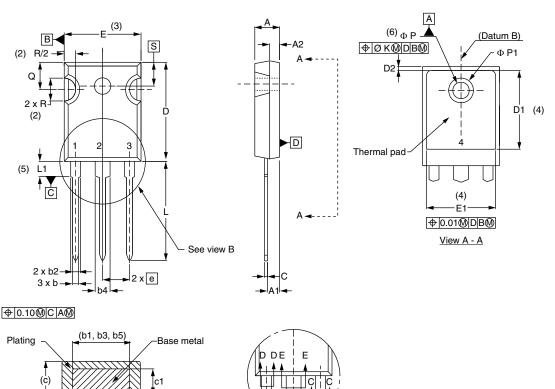
ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-30CPU04LHN3	25	500	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?95626				
Part marking information <u>www.vishay.com/doc?95007</u>				



TO-247AD 3L

DIMENSIONS in millimeters and inches



Section C - C, D - D, E - E								
SYMBOL	MILLIN	IETERS	INC	INCHES				
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES			
Α	4.65	5.31	0.183	0.209				
A1	2.21	2.59	0.087	0.102				
A2	1.50	2.49	0.059	0.098				
b	0.99	1.40	0.039	0.055				

0.039

0.065

0.065

0.102

0.102

0.015

0.015

0.776

0.515

0.053

0.094

0.092

0.135

0.133

0.035

0.033

0.815

(h h2 h4)

:5	

View B

SYMBOL	IVIILLIIV	ILILING	INOTILS		NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46 BSC		0.215	BSC	
ØΚ	0.254		0.010		
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217 BSC		
•	•		•		•

INCHES

MILLIMETERS

Notes

b1

b2

b3

b4

b5

С

с1

D

D1

(1) Dimensioning and tolerancing per ASME Y14.5M-1994

1.35

2.39

2.34

3.43

3.38

0.89

0.84

20.70

- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body

3

- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1

0.99

1.65

1.65

2.59

2.59

0.38

0.38

19.71

13.08

- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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